# Understanding the Role of Confined Carriers in Nanotipped Thermionic Emitters



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# **Conversion Efficiency of Thermionic Emitters**



Low work function or high operating temperature to obtain comparable efficiencies to Organic Rankine Cycles (ORC).



Transition metals have increasing trend as orbitals fill. Alkali metals have lowest work function values. Lanthanides has moderate workfunction.

100 Intrisic workfunctions of solid materials ordered by atomic weight. Lower values are best. 90 Normalized Workfunction ( $\Phi/k_BT_m$ ) [eV/eV] 80 70 60 50 Carbon and tungsten prove to be the lowest elements. 40 30 20 10 Li Be B C Na Mg Al Si K Ca Sc Ti V Cr Mn Fe Ni Co Cu Zn Ga As Se Rb Sr Y Zr Nb Mo Ru Rh Pd Ag Cd In Sn Sb Te Cs Ba La Ce Nd Sm Eu Gd Tb Yb Lu Hf Ta W Re Os Ir Pt Au Hg Ti Pb Bi Th U T<sub>m</sub> = Melting Temperature Periodic Element

Dividing the work function by the melting temperature reveals carbon and tungsten to be the lowest.



Over the last 25 years there has not been a huge improvement in identifying 5 lower work function materials. Scandate and diamond prove to be lowest.

# Historical Literature Perspective of Current Density



Over the last decade there has been a significant increase in current density. This is reasoned to be a results of geometric and fabrication influences.

# Understanding the Role of Confined Carriers



A two dimensional quantum model is used to predict the influence of the tip geometry on the emission characteristics.

# **Thermionic Emission**



In pure thermionic emission the current is above the vacuume level. Discrete states result in discrete peaks in current.



In thermal-field emission tunneling current below the vacuum level results in <sup>9</sup> increased overall current.



Thermionic model provides more accurate description of emission current along with the ability to predict the on-set of thermionic emission.

### Thermionic Heat Flux or Power from Thin Film



The electronic heat flux or thermionic power can be predicted using the calculated spectral density and kinetic energy of carriers.



Under combined thermionic and field emission the current increases with increase tunneling current due to band bending.



The emission power results in lower temperature field emission as a results of the field enhancment of the nanotip geometry.

### Nanotipped Spatial Charge Density – Tip Width









Charge

Density



1e-09 2e-09 3e-09 4e-09 5e-09 6e-09 7e-09 8e-09

Cross-Plane Device Length [m]

0

T=0K

#### Nanotip Geometry w=6nm l=2nm

Charge

Density

2e+15

As transverse confinement relaxes the charge density increases and becomes more continuous. Potential plot shows peaks near edge and base.



Slight increase with tip width. Reasoned to be heavily influences by charge density.

# Nanotipped Spatial Charge Density – Tip Length





Increase emission with tip emitter compared to thin film however the emission is not heavily dependent on the length.

# Nanotipped Spatial Charge Density – Temperature

Univ.

Lab, West Virginia

Science

Materials

omputational



Highest charge distribution near edge and scales by Fermi Dist.

#### Conclusion

Workfunction values have been steady over the past 25 year however there has been a large improvement of current density. This was reasoned to be a result of fabrication (lower interface resistance) and geometric improvements.

The thermionic emission current did have a marginal improvement with the addition of the tip (2-6nm).

The governing factor for the improvement was more than likely the increase in charge density as the confinement relaxed states. The relaxation in the transverse direction proved most beneficial.

Density plots confirm that the charge density within the nanotip are not localized exclusively near the tip. This might be an avenue for further investigation.

Future investigations will look at larger tip geometries approaching the continuum regime. Run GPU code on XCEDE.

Investigate specific device constructions. Ex: material, dimensions, gate voltage.

Look at the the confinement of a wide band gap material on surface.





